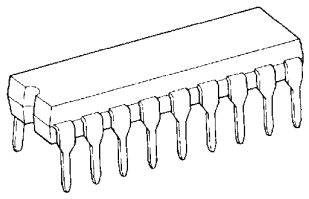
TOSHIBA Bipolar Digital Integrated Circuit Silicon Monolithic

ULN2803APG,ULN2803AFWG,ULN2804APG,ULN2804AFWG (Manufactured by Toshiba Malaysia)

8ch Darlington Sink Driver

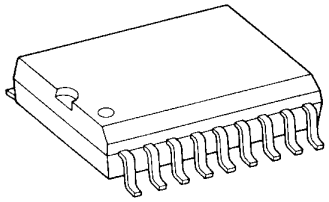
The ULN2803APG / AFWG Series are high−voltage, high−current darlington drivers comprised of eight NPN darlington pairs.
All units feature integral clamp diodes for switching inductive loads.
Applications include relay, hammer, lamp and display (LED) drivers.
The suffix (G) appended to the part number represents a Lead (Pb)-Free product.

ULN2803APG
ULN2804APG



DIP18-P-300-2.54F

ULN2803AFWG
ULN2804AFWG



SOL18-P-300-1.27

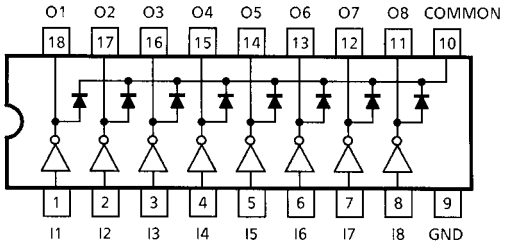
Weight
DIP18−P−300−2.54F: 1.478 g (Typ.)
SOL18−P−300−1.27 : 0.48 g (Typ.)

Features

- Output current (single output)
  500 mA (Max.)
- High sustaining voltage output
  50 V (Min.)
- Output clamp diodes
- Inputs compatible with various types of logic.
- Package Type−APG : DIP−18pin
- Package Type−AFWG : SOL−18pin

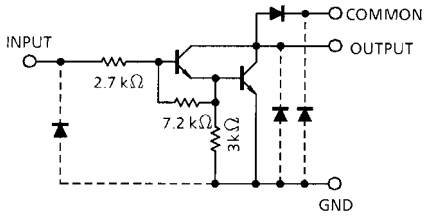
Type	Input Base Resistor	Designation
ULN2803APG / AFWG	2.7 kΩ	TTL, 5 V CMOS
ULN2804APG / AFWG	10.5 kΩ	6~15 V PMOS, CMOS

Pin Connection (top view)

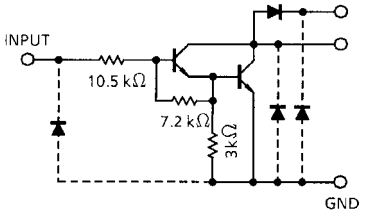


Schematics (each driver)

ULN2803APG / AFWG



ULN2804APG / AFWG



Note: The input and output parasitic diodes cannot be used as clamp diodes.

Absolute Maximum Ratings (Ta = 25°C)

Characteristic		Symbol	Rating	Unit
Output sustaining voltage		$V_{CE\ (SUS)}$	−0.5~50	V
Output current		I_{OUT}	500	mA / ch
Input voltage		V_{IN}	−0.5~30	V
Clamp diode reverse voltage		V_R	50	V
Clamp diode forward current		I_F	500	mA
Power dissipation	APG	P_D	1.47	W
	AFWG		0.92 / 1.31 (Note)	
Operating temperature		T_{opr}	−40~85	°C
Storage temperature		T_{stg}	−55~150	°C

Note: On Glass Epoxy PCB (75 × 114 × 1.6 mm Cu 20%)

Recommended Operating Conditions (Ta = −40~85°C)

Characteristic		Symbol	Test Condition	Min	Typ.	Max	Unit
Output sustaining voltage		$V_{CE\ (SUS)}$		0	—	50	V
Output current	APG	I_{OUT}	T_{pw} = 25 ms, Duty = 10%, 8 Circuits	0	—	347	mA / ch
			T_{pw} = 25 ms, Duty = 50%, 8 Circuits	0	—	123	
	AFWG		T_{pw} = 25 ms, Duty = 10%, 8 Circuits	0	—	268	
			T_{pw} = 25 ms, Duty = 50%, 8 Circuits	0	—	90	
Input voltage		V_{IN}		0	—	30	V
Input voltage (Output on)	ULN2803A	$V_{IN\ (ON)}$		3.5	—	30	V
	ULN2804A			8	—	30	
Clamp diode reverse voltage		V_R		—	—	50	V
Clamp diode forward current		I_F		—	—	400	mA
Power dissipation	APG	P_D	Ta = 85°C	—	—	0.76	W
	AFWG		Ta = 85°C (Note)	—	—	0.48	

Note: On Glass Epoxy PCB (75 × 114 × 1.6 mm Cu 20%)

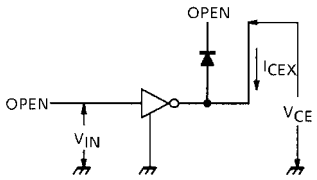
Electrical Characteristics (Ta = 25°C)

Characteristic		Symbol	Test Cir−Cuit	Test Condition		Min	Typ.	Max	Unit
Output leakage current		I_{CEX}	1	V_{CE} = 50 V	Ta = 25°C	—	—	50	μA
				V_{CE} = 50 V	Ta = 85°C	—	—	100	
	ULN2804A			V_{CE} = 50 V	V_{IN} = 1 V	—	—	500	
Collector−emitter saturation voltage		VCE (sat)	2	I_{OUT} = 350 mA, I_{IN} = 500 μA		—	1.3	1.6	V
				I_{OUT} = 200 mA, I_{IN} = 350 μA		—	1.1	1.3	
				I_{OUT} = 100 mA, I_{IN} = 250 μA		—	0.9	1.1	
Input current	ULN2803A	$I_{IN\ (ON)}$	2	V_{IN} = 3.85 V		—	0.93	1.35	mA
	ULN2804A			V_{IN} = 5 V		—	0.35	0.5	
				V_{IN} = 12 V		—	1.0	1.45	
		$I_{IN\ (OFF)}$	4	I_{OUT} = 500 μA, Ta = 85°C		50	65	—	μA
Input voltage (Output on)	ULN2803A	$V_{IN\ (ON)}$	5	V_{CE} = 2 V, I_{OUT} = 200 mA		—	—	2.4	V
				V_{CE} = 2 V, I_{OUT} = 250 mA		—	—	2.7	
				V_{CE} = 2 V, I_{OUT} = 300 mA		—	—	3.0	
	ULN2804A			V_{CE} = 2 V, I_{OUT} = 125 mA		—	—	5.0	
				V_{CE} = 2 V, I_{OUT} = 200 mA		—	—	6.0	
				V_{CE} = 2 V, I_{OUT} = 275 mA		—	—	7.0	
				V_{CE} = 2 V, I_{OUT} = 350 mA		—	—	8.0	
DC current transfer ratio		h_{FE}	2	V_{CE} = 2 V, I_{OUT} = 350 mA		1000	—	—	
Clamp diode reverse current		I_R	6	Ta = 25°C	(Note)	—	—	50	μA
				Ta = 85°C	(Note)	—	—	100	
Clamp diode forward voltage		V_F	7	I_F = 350 mA		—	—	2.0	V
Input capacitance		C_{IN}	—			—	15	—	pF
Turn−on delay		t_{ON}	8	R_L = 125 Ω, V_{OUT} = 50 V		—	0.1	—	μs
Turn−off delay		t_{OFF}		R_L = 125 Ω, V_{OUT} = 50 V		—	0.2	—	

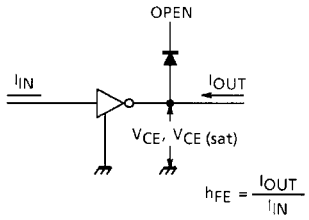
Note: $V_R = V_R$ MAX.

Test Circuit

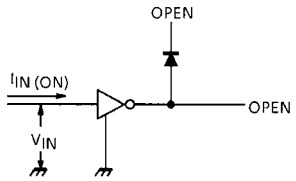
1. I_{CEX}



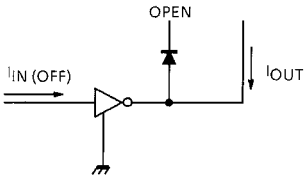
2. $V_{CE\ (sat)}$, h_{FE}



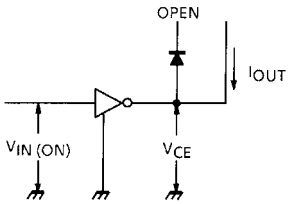
3. $I_{IN\ (ON)}$



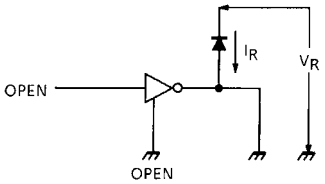
4. $I_{IN\ (OFF)}$



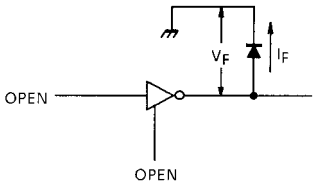
5. $V_{IN\ (ON)}$



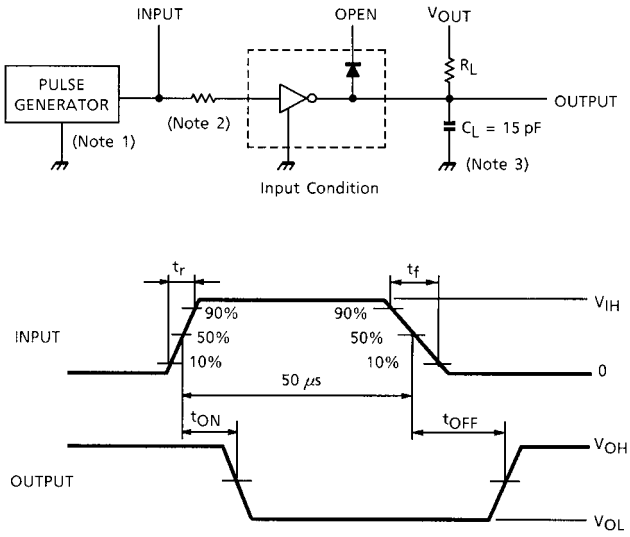
6. I_R



7. V_F



8. t_{ON}, t_{OFF}



Note 1: Pulse Width 50 μs, Duty Cycle 10%
Output Impedance 50 Ω, $t_r \leq 5$ ns, $t_f \leq 10$ ns

Note 2: See below.

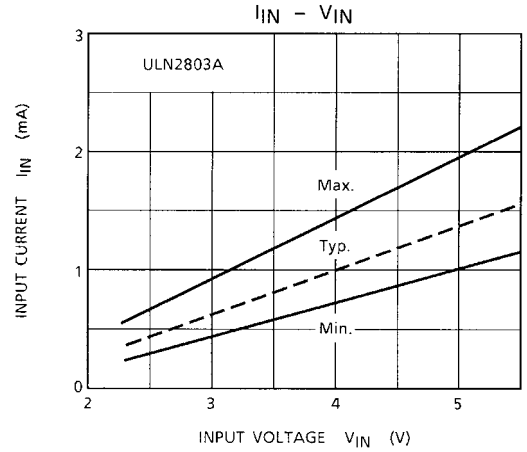
Input Condition

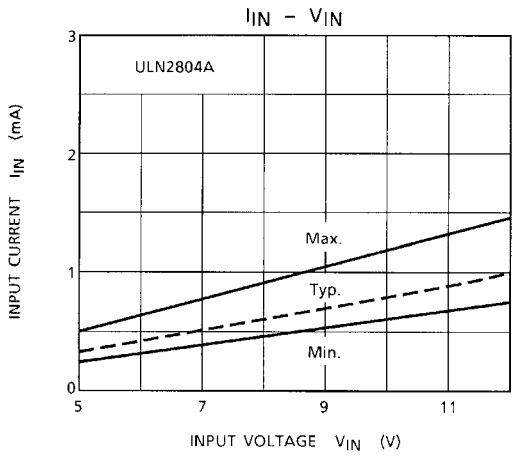
Type Number	R1	V_{IH}
ULN2803A	0Ω	3 V
ULN2804A	0Ω	8 V

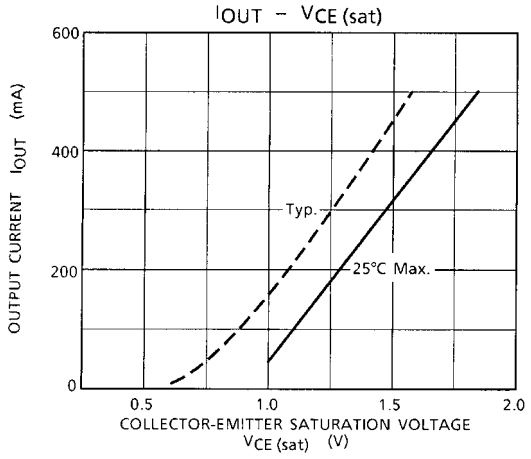
Note 3: C_L includes probe and jig capacitance

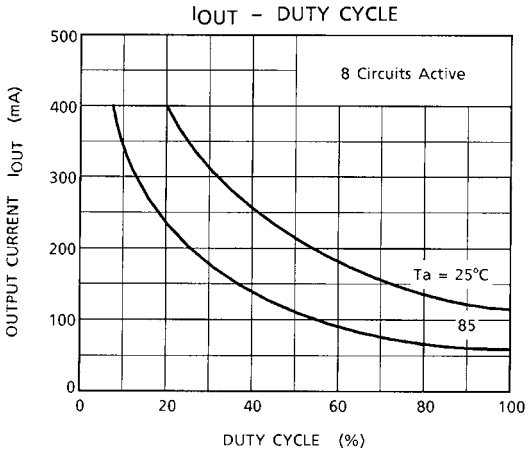
Precautions for Using

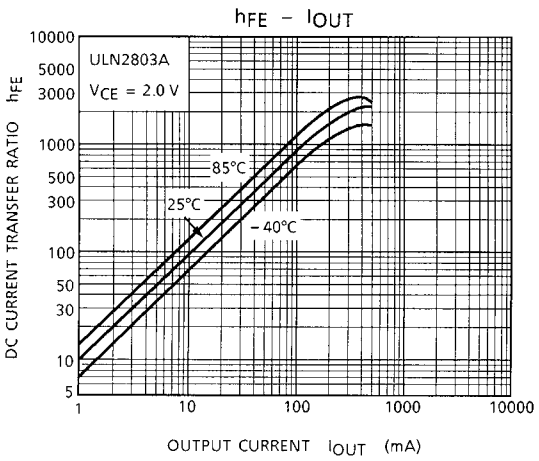
This IC does not integrate protection circuits such as overcurrent and overvoltage protectors.
Thus, if excess current or voltage is applied to the IC, the IC may be damaged. Please design the IC so that excess current or voltage will not be applied to the IC.
Utmost care is necessary in the design of the output line, COMMON and GND line since IC may be destroyed due to short−circuit between outputs, air contamination fault, or fault by improper grounding.

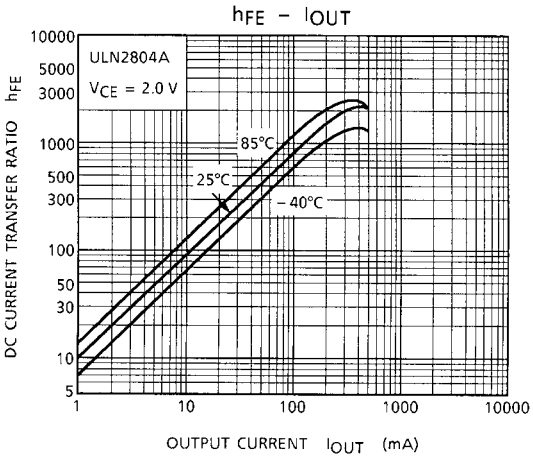

I_{IN} – V_{IN}
ULN2803A
Max.
Typ.
Min.
INPUT CURRENT I_{IN} (mA)
INPUT VOLTAGE V_{IN} (V)

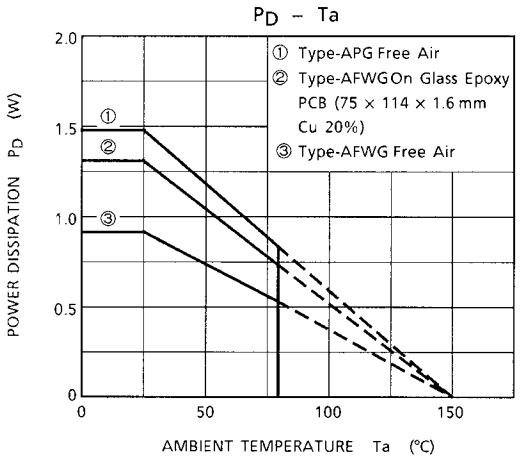

I_{IN} – V_{IN}
ULN2804A
Max.
Typ.
Min.
INPUT CURRENT I_{IN} (mA)
INPUT VOLTAGE V_{IN} (V)


I_{OUT} – V_{CE} (sat)
Typ.
25°C Max.
OUTPUT CURRENT I_{OUT} (mA)
COLLECTOR-EMITTER SATURATION VOLTAGE
V_{CE} (sat) (V)


I_{OUT} – DUTY CYCLE
8 Circuits Active
Ta = 25°C
85
OUTPUT CURRENT I_{OUT} (mA)
DUTY CYCLE (%)

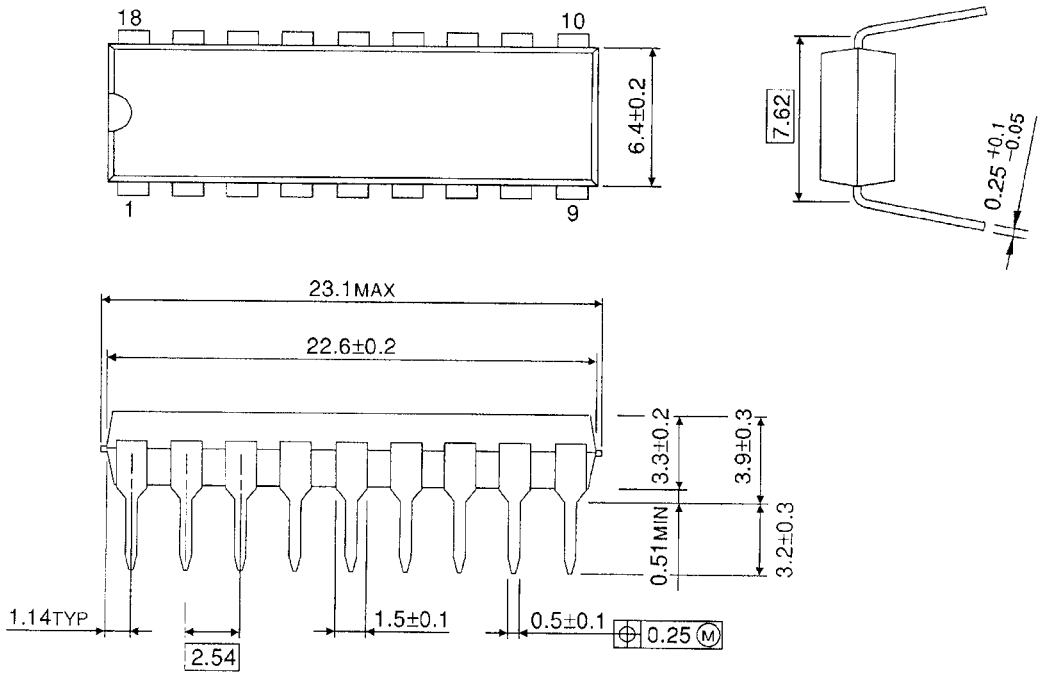

h_{FE} – I_{OUT}
ULN2803A
V_{CE} = 2.0 V
85°C
25°C
– 40°C
DC CURRENT TRANSFER RATIO h_{FE}
OUTPUT CURRENT I_{OUT} (mA)


h_{FE} – I_{OUT}
ULN2804A
V_{CE} = 2.0 V
85°C
25°C
– 40°C
DC CURRENT TRANSFER RATIO h_{FE}
OUTPUT CURRENT I_{OUT} (mA)


P_D – Ta
① Type-APG Free Air
② Type-AFWG On Glass Epoxy PCB (75 × 114 × 1.6 mm Cu 20%)
③ Type-AFWG Free Air
POWER DISSIPATION P_D (W)
2.0
1.5
1.0
0.5
0
0
50
100
150
AMBIENT TEMPERATURE Ta (°C)

Package Dimensions

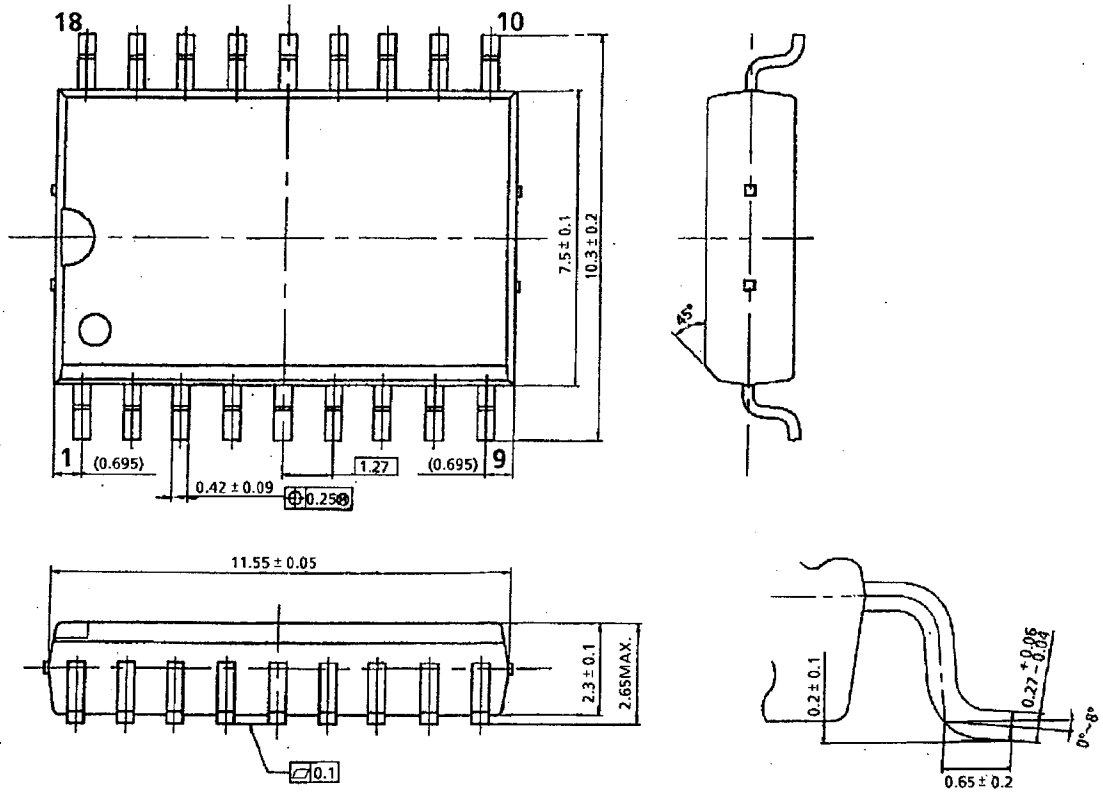
DIP18−P−300−2.54F Unit: mm



Weight: 1.478 g (Typ.)

Package Dimensions

SOL18−P−300−1.27 Unit: mm



Weight: 0.48 g (Typ.)